



NV-CMM-E3S Memory Module

SMART's NV-CMM-E3S non-volatile memory module with built-in backup power source utilizes the Compute Express Link (CXL)® 2.0 standard in an E3.S 2T form factor. It uses a CXL x8 CXL controller as well as a SMART NV-CXL Controller and 2Rx4 Buffered DDR4 DRAM, which allows the host to access the DRAM via the CXL x8 interface during runtime. In the event of a catastrophic failure, the module will back up the DRAM data into the NAND devices using power from its onboard Energy Source Module (ESM). When power is restored, the NV-CMM-E3S will then copy data from the NAND devices to the DRAM in order to enable continuous operation.

Key Features

- Form Factor: E3.S 2T (112.75mm x 15mm x 76mm)
- Density: 32GB with 16Gb DRAM
- Performance: ~200ns Round Trip Latency with Throughput of 32GB/s
- Host CXL Interface using Microchip Controller
 - CXL Type 3 memory
 - Supports CXL 1.1/2.0
 - Configured for CXL x8 Gen 5
 - Out-of-Band (OOB) Interfaces: SMBus (I2C), SPI, and UART
 - Enterprise Class RAS features
 - End-to-end data path integrity with overlapping parity/ECC
 - SECDED ECC support to DDR
 - Reed-Solomon ECC support to DDR
 - Secure boot and Secure firmware update
 - CXL IDE
- Persistent Memory Features
 - ASIC and FPGA based Controllers
 - Non-Volatile storage via Backup to NAND
 - Onboard Energy Source Module (ESM) for backup power
 - AES-256 data encryption for data at rest



- Power Consumption
 - Active: TBD
 - Backup: ~11 watts (estimate)
- Ambient Operating Temperature: 40°C max

Key Features

- System acceleration – check pointing, caching, etc.
- Large in-memory databases
- Quick data recovery following power loss or system hang/crash

Benefits

- Non-Volatile CXL Memory Expansion
- Low latency, high bandwidth persistent storage
- Embedded energy source so complete solution if fully self-contained
- Takes advantage of CXL “Global Persistent Flush” (GPF) feature to implement persistence

Pinout

This module is compliant with EDSFF Electrical specification for E3.S x4 interfaces as defined in SFF-TA-1009 (Rev-3.0).

Ordering Information

NV-CMM		
SMART Part Number	Density	Description
STXBB32GNM44S18MF	32GB	CXL 2.0, E3.S 2T, DDR4-3200

Contact: Arthur Sainio at Arthur.Sainio@smartm.com for any sales and sampling queries.



For more information, please visit: www.smartm.com

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